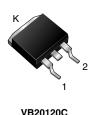


Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.54 \text{ V}$ at $I_F = 5 \text{ A}$





VB20120)C
PIN 1 O	K
	— 0
PIN 2 O	HEATSINK

PRIMARY CHARACTERISTICS			
Package	TO-263AB		
I _{F(AV)}	2 x 10 A		
V_{RRM}	120 V		
I _{FSM}	120 A		
V_F at $I_F = 10 A$	0.64 V		
T _J max.	150 °C		
Diode variation	Common cathode		

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

RoHS COMPLIANT HALOGEN

FREE

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VB20120C	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	120	V
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	20	А
	per diode		10	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	120	
Voltage rate of change (rated V _R)		dV/dt	10 000	
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150	°C

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 5 A	- T _A = 25 °C	V _F	0.62	-	V	
	I _F = 10 A			0.81	0.90		
	I _F = 5 A	T _A = 125 °C		0.54	-		
	I _F = 10 A			0.65	0.72		
Reverse current per diode (2)	V _R = 90 V	T _A = 25 °C		8	-	μΑ	
	v _R = 90 v	T _A = 125 °C 6	-	mA			
	V _R = 120 V	T _A = 25 °C	I _R	ı	700	μΑ	
	V _R = 120 V	T _A = 125 °C		14	45	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	VB20120C	UNIT
Typical thermal resistance per diode	$R_{ heta JC}$	2.8	°C/W

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB20120SC-M3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VB20120SC-M3/8W	1.38	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

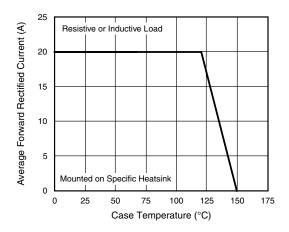


Fig. 1 - Maximum Forward Current Derating Curve

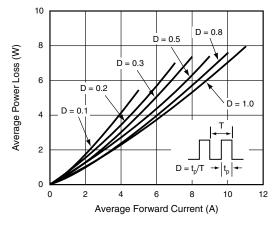


Fig. 2 - Forward Power Loss Characteristics Per Diode

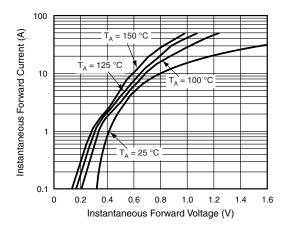


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

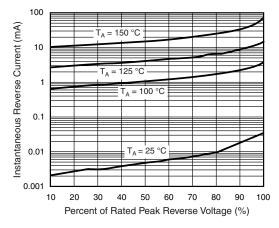


Fig. 4 - Typical Reverse Characteristics Per Diode



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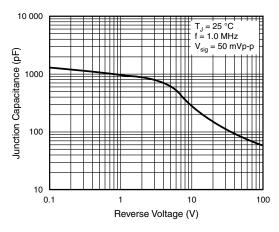


Fig. 5 - Typical Junction Capacitance Per Diode

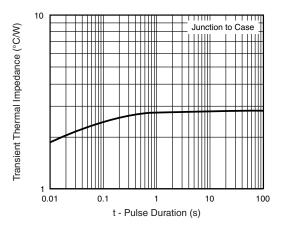
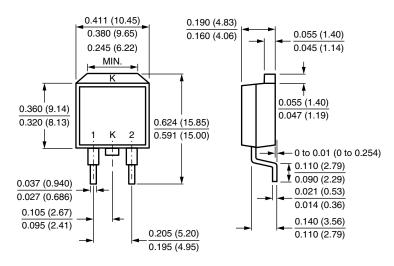


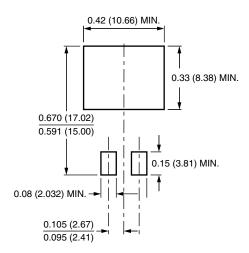
Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB



Mounting Pad Layout





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